

TDA2040

25-watt hi-fi audio power amplifier

Datasheet – production data

Features

- Wide-range supply voltage, up to 40 V
- Single or split power supply
- Short-circuit protection to ground
- Thermal shutdown
- $P_0 = 25 \text{ W}$ @ THD = 0.5%, $V_S = \pm 17 \text{ V}$, $R_L = 4 \Omega$
- $P_0 = 30$ W @ THD =10%, $V_S = \pm 17$ V, $R_L = 4$ Ω

Description

The TDA2040 is a monolithic integrated circuit in the Pentawatt[®] package, intended for use as an audio class-AB amplifier. Typically, it provides 25 W output power into 4 Ω with THD = 0.5% at V_S = 34 V. The TDA2040 provides high output current and has very low harmonic and crossover distortion. Furthermore, the device incorporates a patented short-circuit protection system



comprising an arrangement for automatically limiting the dissipated power so as to keep the operating point of the output transistors within their safe operating range. A thermal shutdown system is also included.

Table 1. Device summary

Order code	Package	
TDA2040V	Pentawatt V (vertical)	



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This is information on a product in full production.

Pin connections 1



Schematic diagram



Electrical specifications 2

2.1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter		Unit		
Vs	Supply voltage	±20	V		
Vi	Input voltage	Vs			
Vi	Differential input voltage	±15			V
lo	Output peak current (internally limited)	4			А
P _{tot}	Power dissipation at Tcase = 75 °C	25			W
T _{stg} , T _j	Storage and junction temperature	-40 to 150			°C
V _{ESD_HBM}	ESD maximum withstanding voltage range, test condition CDF-AEC-Q100-002- "Human body model"	±1500			V
Thermal data					
Symbol	Parameter	Min	Тур	Max	Unit

2.2 **Thermal data**

Table 3. Thermal data

	Symbol	Parameter	Min	Тур	Max	Unit
	R _{th_j-case}	Thermal resistance junction to case	-	-	3	°C/W
005018	ie P'	Coducit				
0.						



2.3 Electrical characteristics

The specifications given here were obtained with the conditions V_S = ±16 V, T_{amb} = 25 °C unless otherwise specified.

Syr	nbol	Parameter	Test conditions	Min	Тур	Max	Unit
١	∕s	Supply voltage	-	±4.5	-	±20	V
	I _d	Quiescent drain current	$V_{S} = \pm 4.5 V$ $V_{S} = \pm 20 V$	-	- 45	30 100	mA mA
	I _b	Input bias current	$V_{S} = \pm 20 \text{ V}$	-	0.3	1	μA
V	'os	Input offset voltage	V _S = ±20 V	-	±2	±20	mV
I,	OS	Input offset current	-	-	. (±200	nA
			d = 0.5%, f = 1 kHz, T_{amb} = 60 °C R_L = 4 Ω R_L = 4 Ω , V_S = ±17 R_I = 8 Ω	20	22 25 12	-	
Po	Output power	d = 0.5%, f = 15 kHz; T _{amb} = 60 °C R _L = 4 Ω R _L = 4 Ω, V _S = ±17 d = 10%, f = 1 kHz B _L = 4 Ω, V _S = ±17	15	18 20 30	-	W	
B	3W	Power bandwidth	$P_{0} = 1 \text{ W}, $	-	100	-	Hz
G	vOI	Voltage gain (open loop)	f = 1 kHz	-	80	-	dB
(G _v	Voltage gain (closed loop)	f = 1 kHz	29.5	30	30.5	dB
	d	Total harmonic distortion	$P_{o} = 0.1$ to 10 W, $R_{L} = 4 Ω$, f = 40 to 15000 Hz	-	0.08	-	%
		$P_o = 0.1$ to 10 W, $R_L = 4 \Omega$, $f = 1 \text{ kHz}$	-	0.03	-	%	
e	∍ _N	Input noise voltage	B = Curve A B = 22 Hz to 22 kHz	-	2 3	- 10	μV
0	IN	Input noise current	B = Curve A B = 22 Hz to 22 kHz	-	50 80	- 200	pА
	R _i	Input resistance (pin 1)	-	0.5	5	-	MΩ
SV	/RR	Supply voltage rejection ratio	G_V = 30 dB, R_L = 4 Ω , R_g = 22 k Ω , f = 100 Hz V _{ripple} = 0.5 V RMS	40	50	-	dB
	h	Efficiency	f = 1 kHz P _o = 12 W, R _L = 8 Ω P _o = 22 W, R _L = 4 Ω	-	66 63	-	%
	Tj	Thermal shutdown junction temperature	-	-	-	145	°C

Table 4.Electrical characteristics



2.4 Characterizations





Figure 7. Distortion vs. frequency



Figure 8. SVRR vs. frequency



Figure 9. SVRR vs. voltage gain





Figure 10. Quiescent drain current vs. supply Figure 11. Open loop gain vs. frequency voltage









3 Applications

3.1 Circuits and PCB layout

Figure 13. Amplifier with split power supply



Figure 14. PCB and components layout for the circuit of the amplifier with split power supply







Figure 15. Amplifier with single power supply









Figure 17. 30-watt bridge amplifier with split power supply

Figure 18. PCB and components layout for the circuit of the 30-watt bridge amplifier with split power supply







Figure 19. Two-way hi-fi system with active crossover

Figure 20. PCB and components layout for the circuit of the two-way hi-fi system with active crossover



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3.2 Multiway speaker systems and active boxes

Multiway loudspeaker systems provide the best possible acoustic performance since each loudspeaker is specially designed and optimized to handle a limited range of frequencies. Commonly, these loudspeaker systems divide the audio spectrum into two, three or four bands.



To maintain a flat frequency response over the hi-fi audio range the bands covered by each loudspeaker must overlap slightly. Any imbalance between the loudspeakers produces unacceptable results, therefore, it is important to ensure that each unit generates the correct amount of acoustic energy for its segment of the audio spectrum. In this respect it is also important to know the energy distribution of the music spectrum (see *Figure 22*) in order to determine the cutoff frequencies of the crossover filters. As an example, a 100-W three-way system with crossover frequencies of 400 Hz and 3 kHz would require 50 W for the woofer, 35 W for the midrange unit and 15 W for the tweeter.

Both active and passive filters can be used for crossovers but today active filters cost significantly less than a good passive filter using air-cored inductors and non-electrolytic capacitors. In addition, active filters do not suffer from the typical defects of passive filters:

- power loss
- increased impedance seen by the loudspeaker (lower damping)
- difficulty of precise design due to variable loudspeaker impedance

Obviously, active crossovers can only be used if a power amplifier is provided for each drive unit. This makes it particularly interesting and economically sound to use monolithic power amplifiers.

In some applications, complex filters are not really necessary and simple RC low-pass and high-pass networks (6 dB/octave) can be recommended. The results obtained are excellent because this is the best type of audio filter and the only one free from phase and transient distortion. The rather poor out-of-band attenuation of single RC filters means that the loudspeaker must operate linearly well beyond the crossover frequency to avoid distortion.







A more effective solution, named "Active Power Filter" by STMicroelectronics, is shown in *Figure 23.* The proposed circuit can be realized by combined power amplifiers and 12-dB/octave or 18-dB/octave high-pass or low-pass filters.

The component values calculated for fc = 900Hz using a Bessel 3rd order Sallen and Key structure are:

C1 = C2 = C3 = 22 nF $R1 = 8.2 \text{ k}\Omega$ $R2 = 5.6 k\Omega$ $R3 = 33 k\Omega$

In the block diagram of Figure 24 is represented an active loudspeaker system completely realized using power integrated circuit, rather than the traditional discrete transistors on hybrids, very high quality is obtained by driving the audio spectrum into three bands using active crossovers (TDA2320A) and a separate amplifier and loudspeakers for each band. A modern subwoofer/midrange/tweeter solution is used.

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3.3 Practical considerations

3.3.1 Printed circuit board

The layout shown in *Figure 14* should be adopted by the designers. If different layouts are used, the ground points of input 1 and input 2 must be well decoupled from the ground return of the output in which a high current flows.

3.3.2 Assembly suggestion

No electrical isolation is needed between the package and the heatsink with single supply voltage configuration.

3.3.3 Application suggestions

The recommended values of the components are those shown in the application circuit of *Figure 13*. However, if different values are chosen then the following table can be helpful.

	Component	Recommended value	Purpose	Larger than recommended value	Smaller than recommended value
	R1	22 kΩ	Non-inverting input biasing	Increase in input impedance	Decrease in input impedance
	R2	680 Ω	Closed-loop gain setting	Decrease in gain ⁽¹⁾	Increase in gain
	R3	22 kΩ	Closed-loop gain setting	Increase in gain	Decrease in gain ⁽¹⁾
	R4	4.7 Ω	Frequency stability	Danger of oscillation at high frequencies with inductive loads	-
	C1	1 μF	Input DC decoupling	-	Increase in low-frequency cut-off
10	C2	22 µF	Inverting DC decoupling	-	Increase in low-frequency cut-off
0050.	C3, C4	0.1 µF	Supply voltage bypass	-	Danger of oscillation
	C5, C6	220µF	Supply voltage bypass	-	Danger of oscillation
	C7	0.1µF	Frequency stability	-	Danger of oscillation

Table 5. Variations from recommended values

1. The value of closed loop gain must be higher than 24 dB



4 Package mechanical data



In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.



5 Revision history

Table 6.	Document	revision	history
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	Date	Revision	Changes
	Apr-2003	3	Changes not recorded
	28-Oct-2010	4	Added features list on page 1 Updated minimum supply voltage to ±4.5 V in <i>Table 4 on page 4</i> Corrected the title of <i>Figure 15 on page 8</i> Updated presentation
	16-Jun-2011	5	Removed minimum value from Pentawatt (vertical) package dimension H3 (<i>Figure 25</i>); minor textual changes.
	17-Jul-2012	6	Updated output power throughout datasheet (title, <i>Features</i> , <i>Description</i> , <i>Table 4</i>).
obsole	tepro	ductl	obsolete



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